Approved for use through 11200000 (000 B051-0031)

U.S. Patent and Training Training

INFORMATION DISCLOSURE
STATEMENT BY APPLICANT

(Not for submission under 37 CFR 1.99)

	Application Number		10596573					
	Filing Date		2006-06-16					
	First Named Inventor	Zhong	-Xiang He, et al.					
	Art Unit							
	Examiner Name							
Attorney Docket Number		er	BUR920030081US1					

			Remove								
Examiner Initial*	Cite No Patent Number		Kind Code ¹	Issue Date		Name of Pate of cited Docu	Pages, Columns, Lir Relevant Passages Figures Appear				
	1	4933297		1990-06	S-12	Lu					
	2	5563433		1996-10-08		Nagata, et al.					
	3	5714793		1998-02-03		Cartagena, et a					
	4	6157068		2000-12-05		Hashimoto, et					
If you wis	h to a	dd additional U.S. Pater	nt citatio	n inform	ation pl	ease click the	Add button.		Add		
			U.S.P	ATENT	APPLI	CATION PUBL	ICATIONS		Remove		
Examiner Initial*	Cite No	Publication Number	Kind Code ¹	Publica Date	ition	Name of Pate of cited Docu	Pages,Columns,Lines where Relevant Passages or Relevant Figures Appear				
	1	20020050627		2002-05-02		Zambrano					
If you wis	h to ac	⊥dd additional U.S. Publi	shed Ap	plication	citation	ı n information p	lease click the Ad	d button	Add		
				FOREIG	3N PAT	ENT DOCUM	ENTS		Remove		
Examiner Initial*	Cite No	Foreign Document Number ³	Country Code ²			Publication Date	Name of Patente Applicant of cited Document	e or V	Pages,Columns,Lines where Relevant Passages or Relevant Figures Appear		

Receipt date: 11/15/2007				Applicat	ion Number		10596573 1	0596	573	- GA	ιU: 2	826	
					Filing D	ate		2006-06-16					
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Not for submission under 37 CFR 1.99)				First Na	med Inventor	Zhor	ng-Xiang He, et al.						
				Art Unit									
				Examin	er Name	Т							
					Attorney Docket Number			BUR920030081US1					
						6.0			7.1				
	1	DE10	142690A1	DE		2003-03-	27						
If you wis	h to a	dd add	litional Foreign	Patent Do	cument ci	tation informat	on ple	ase click the Add but	ton _	Add]		
				NON	-PATENT	LITERATUR	DOC	UMENTS	Re	move	1		
Examiner Initials*	Cite No	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, pages(s), volume-issue number(s), publisher, city and/or country where published.										T5	
	1	HAFIZI M: "New Submicron HBT IC Technology Demonstrates Ultra-Fast, Low-Power Integrated Circuits" - IEEE Transactions On Electron Devices, IEEE Service Center, Pisacataway, NJ, US, Vol. 45, No. 9, September 1998, pp. 1862 - 1868											
If you wis	h to a	dd add	litional non-pat	ent literatu	re docume	ent citation info	rmatio	n please click the Ac	d buttor	ı A	d d		
					EXA	MINER SIGNA	TURE						
Examiner	Signa	ature	/Vongsa	avanh Sen	gdara/			Date Considered	0	5/21/	2009		
								rmance with MPEP 6				igh a	
¹ See Kind 0	Codes	of USPT	O Patent Documer	nts at www.US	SPTO.GOV	or MPEP 901.04.	² Enter	office that issued the docu	ment, by	the two	o-letter c	ode (Wi	IPO

Standard ST.3). 3 For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 4 Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. 5 Applicant is to place a check mark here if

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /V.S./

English language translation is attached.